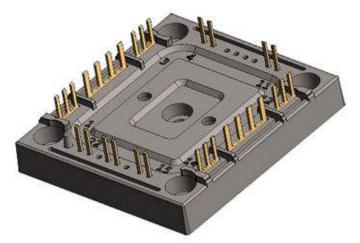
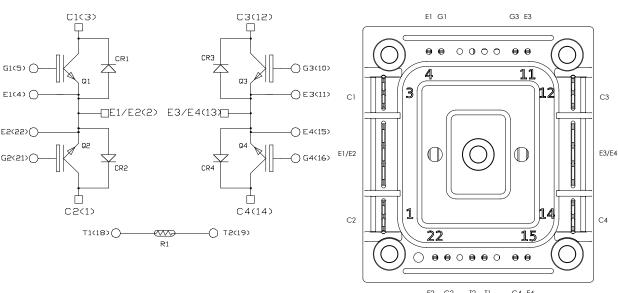
Double Dual Common Emitter High-Speed IGBT4 Power Module

Product Overview

The MSCGLQ75DDU120CTBL3NG device is a 1200 V/75 A double dual common emitter high-speed IGBT4 power module.





All ratings at T_J = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCGLQ75DDU120CTBL3NG device:

- · High speed IGBT4
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- · SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on V_F
- · Ultra-low weight and profile
- Kelvin emitter for easy drive
- Si₃N₄ substrate with thick copper for improved thermal performance
- Internal thermistor for temperature monitoring
- Extended temperature range

Benefits

The following are the benefits of MSCGLQ75DDU120CTBL3NG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-heatsink thermal resistance
- Low profile
- RoHS compliant
- Solderable terminals both for power and signal for easy PCB mounting
- Very integrated power conversion system

Application

The following are the applications of MSCGLQ75DDU120CTBL3NG device:

- · High reliability power systems
- AC switches

Datasheet DS00004078A-page 2

1. Electrical Specifications

This section provides the electrical specifications of MSCGLQ75DDU120CTBL3NG device.

1.1 IGBT4 Characteristics (Per IGBT)

The following table lists the absolute maximum ratings of MSCGLQ75DDU120CTBL3NG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Parameter		Unit
V _{CES}	Collector-Emitter voltage	Emitter voltage 1		V
I _C Continuous collector current		T _H = 25 °C	160	Α
		T _H = 80 °C	75	
I _{CM}	Pulsed collector current	T _H = 25 °C	250	
V _{GE}	Gate-Emitter voltage		±20	V
P _D	Power dissipation	sipation 4		W

The following table lists the electrical characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero gate voltage collector current	V _{GE} = 0 V V _{CE} = 1200 V		_	_	50	μΑ
V _{CE(sat)}	Collector emitter	V _{GE} = 15 V	T _J = 25 °C	1.7	2.05	2.4	V
	saturation voltage	I _C = 75 A	T _J = 150 °C	_	2.6	_	
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$ $I_C = 2.6 \text{ mA}$			5.8	6.3	V
I _{GES}	Gate-Emitter leakage current	V _{GE} = 20 V V _{CE} = 0 V		_	_	150	nA

Electrical Specifications

The following table lists the dynamic characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Condition	าร		Min	Тур	Max	Unit
C _{ies}	Input capacitance	V _{GE} = 0 V			_	4400	_	pF
C _{oes}	Output capacitance	V _{CE} = 25 V	25 V		_	250	_	
C _{res}	Reverse transfer capacitance	f = 1 MHz			_	235	_	
Q _g	Gate charge	$V_{GE} = 15 \text{ V}$ $V_{CE} = 960 \text{ V}$ $I_{C} = 75 \text{ A}$	V _{CE} = 960 V		_	325	_	nC
T _{d(on)}	Turn-on delay time	V _{GE} = ±15 V		T _J = 150 °C	_	30	0 — ns	ns
T _r	Rise time	V _{Bus} = 600 V I _C = 75 A			_	49	_	
T _{d(off)}	Turn-off delay time					366	_	
T _f	Fall time	$R_G = 6.4 \Omega$				48	_	
E _{on}	Turn-on switching energy	V _{GE} = ±15 V V _{Bus} = 600 V		T _J = 150 °C	_	3.84	_	mJ
E _{off}	Turn-off switching energy	$I_{C} = 75 \text{ A}$ $R_{G} = 6.4 \Omega$		T _J = 150 °C	_	3.84	_	
R _G	Integrated gate resist	or			_	10	_	Ω
I _{SC}	Short circuit data		$V_{GE} \le 15 \text{ V}$ $V_{Bus} = 900 \text{ V}$ $t_p \le 10 \mu \text{s}$	T _j = 150 °C	_	260		A
R _{thJH}	Junction-to-heatsink resistance	thermal	$\lambda_{\text{paste}} = 3.4 \text{ W}$	/mK		0.318		°C/W

1.2 SiC Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-4. SiC Diode Ratings and Characteristics

Symbol	Characteristic	Test Condition	ons		Min	Тур	Max	Unit
V _{RRM}	Peak repetitive reverse	voltage			_	_	1200	V
I _{RM}	Reverse leakage	V _R = 1200 V		T _J = 25 °C	_	10	200	μA
	current			T _J = 175 °C	_	250	_	
I _F	DC forward current			T _H = 100 °C	_	50	_	Α
V _F	Diode forward voltage I _F = 50 A			T _J = 25 °C	_	1.5	1.8	V
				T _J = 175 °C	_	2.1	_	
Q _C	Total capacitive charge	V _R = 600 V			_	224	_	nC
С	Total capacitance	f = 1 MHz			_	246	_	pF
		V _R = 400 V						
		f = 1 MHz	f = 1 MHz		_	182	_	
		V _R = 800 V						
R _{thJH}	Junction-to-heatsink the resistance	rmal	$\lambda_{paste} = 3.4 \text{ W/mK}$		_	0.635	_	°C/W

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCGLQ75DDU120CTBL3NG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristic	Characteristic			Тур	Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			2500	_	_	V
T _J	Operating junction temperature r	ange		- 55	_	175	°C
T _{JOP}	Recommended junction temperature under switching conditions			- 55	_	T _{Jmax} –25	
T _{STG}	Storage case temperature			- 55	_	125	
T _C	Operating case temperature			- 55	_	125	
Torque	Mounting torque	To heatsink	M3	0.7	_	0.9	N.m
Wt	Package weight			_	32.5	_	g

The following table lists the temperature sensor NTC of the MSCGLQ75DDU120CTBL3NG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25 °C		_	50	_	kΩ
$\Delta R_{25}/R_{25}$			_	5	_	%
B _{25/85}	T ₂₅ = 298.15 K		_	3952	_	K
ΔΒ/Β	_	T _C = 100 °C	_	4	_	%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.4 Typical IGBT4 Performance Curve (Per IGBT)

This section shows the typical IGBT4 performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-1. Junction-to-Heatsink Thermal Impedance

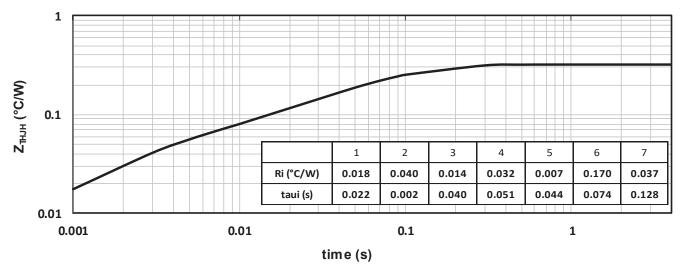


Figure 1-2. Output Characteristics ($V_{GE} = 15 \text{ V}$)

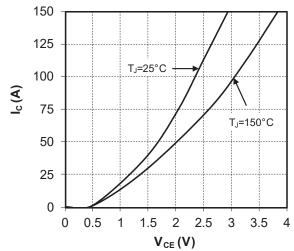


Figure 1-3. Output Characteristics

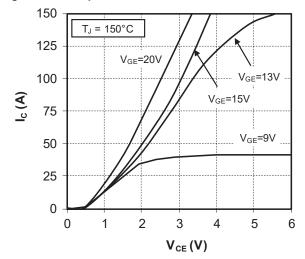


Figure 1-4. Transfer Characteristics

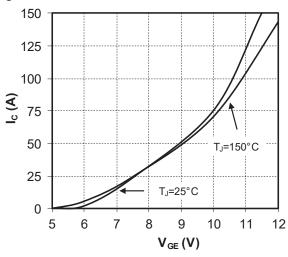


Figure 1-5. Energy Losses vs. Collector Current

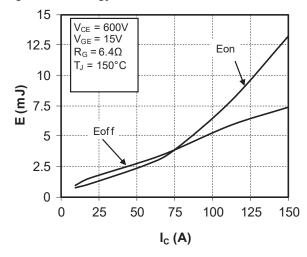


Figure 1-6. Switching Energy Losses vs. Gate Resistance

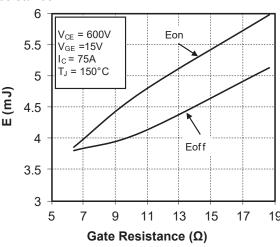
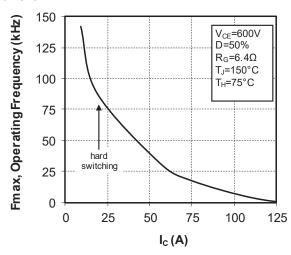


Figure 1-7. Operating Frequency vs. Collector Current



1.5 Typical SiC Diode Performance Curves (Per SiC Diode)

This section shows the typical SiC diode performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-8. Junction-to-Heatsink Thermal Impedance

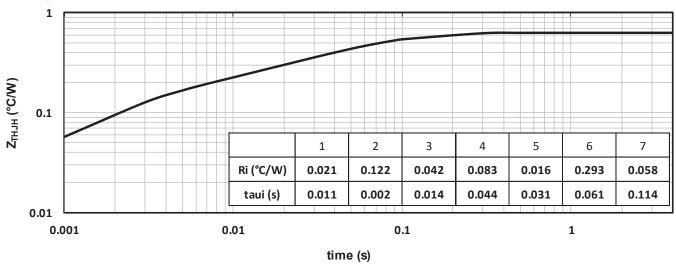


Figure 1-9. Forward Characteristics

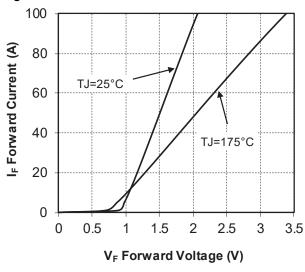
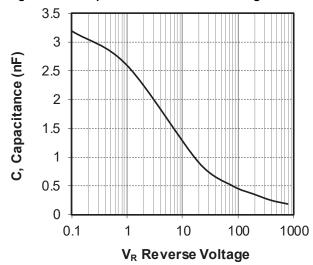


Figure 1-10. Capacitance vs. Reverse Voltage



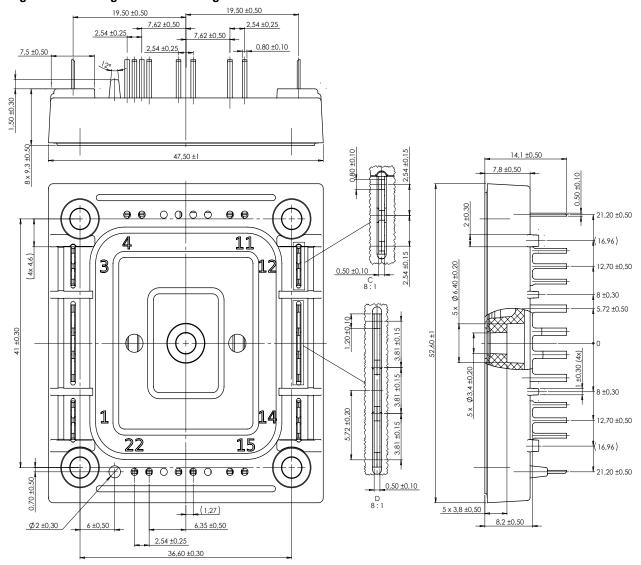
2. Package Specifications

The following section shows the package specification of MSCGLQ75DDU120CTBL3NG device.

2.1 Package Outline

The following figure shows the package outline drawing of MSCGLQ75DDU120CTBL3NG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Datasheet

Revision History

3. Revision History

Revision	Date	Description
A	07/2021	Initial revision

The Microchip Website

Microchip provides online support via our website at www.microchip.com/. This website is used to make files and information easily available to customers. Some of the content available includes:

- Product Support Data sheets and errata, application notes and sample programs, design resources, user's
 guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQs), technical support requests, online discussion groups, Microchip design partner program member listing
- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

Product Change Notification Service

Microchip's product change notification service helps keep customers current on Microchip products. Subscribers will receive email notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, go to www.microchip.com/pcn and follow the registration instructions.

Customer Support

Users of Microchip products can receive assistance through several channels:

- · Distributor or Representative
- · Local Sales Office
- Embedded Solutions Engineer (ESE)
- Technical Support

Customers should contact their distributor, representative or ESE for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in this document.

Technical support is available through the website at: www.microchip.com/support

Microchip Devices Code Protection Feature

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods being used in attempts to breach the code protection features
 of the Microchip devices. We believe that these methods require using the Microchip products in a manner
 outside the operating specifications contained in Microchip's Data Sheets. Attempts to breach these code
 protection features, most likely, cannot be accomplished without violating Microchip's intellectual property rights.
- · Microchip is willing to work with any customer who is concerned about the integrity of its code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code
 protection does not mean that we are guaranteeing the product is "unbreakable." Code protection is constantly
 evolving. We at Microchip are committed to continuously improving the code protection features of our products.
 Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act.
 If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue
 for relief under that Act.

© 2021 Microchip Technology Inc. Datasheet DS00004078A-page 11

Legal Notice

Information contained in this publication is provided for the sole purpose of designing with and using Microchip products. Information regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL OR CONSEQUENTIAL LOSS, DAMAGE, COST OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, Inter-Chip Connectivity, JitterBlocker, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SMART-I.S., storClad, SQI, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2021, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-5224-8446-2

Datasheet DS00004078A-page 12 © 2021 Microchip Technology Inc.

Quality Management System

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.



Worldwide Sales and Service

AMERICAS	ASIA/PACIFIC	ASIA/PACIFIC	EUROPE
Corporate Office	Australia - Sydney	India - Bangalore	Austria - Wels
2355 West Chandler Blvd.	Tel: 61-2-9868-6733	Tel: 91-80-3090-4444	Tel: 43-7242-2244-39
Chandler, AZ 85224-6199	China - Beijing	India - New Delhi	Fax: 43-7242-2244-393
ГеІ: 480-792-7200	Tel: 86-10-8569-7000	Tel: 91-11-4160-8631	Denmark - Copenhagen
Fax: 480-792-7277	China - Chengdu	India - Pune	Tel: 45-4485-5910
echnical Support:	Tel: 86-28-8665-5511	Tel: 91-20-4121-0141	Fax: 45-4485-2829
www.microchip.com/support	China - Chongqing	Japan - Osaka	Finland - Espoo
Web Address:	Tel: 86-23-8980-9588	Tel: 81-6-6152-7160	Tel: 358-9-4520-820
www.microchip.com	China - Dongguan	Japan - Tokyo	France - Paris
Atlanta	Tel: 86-769-8702-9880	Tel: 81-3-6880- 3770	Tel: 33-1-69-53-63-20
Ouluth, GA	China - Guangzhou	Korea - Daegu	Fax: 33-1-69-30-90-79
el: 678-957-9614	Tel: 86-20-8755-8029	Tel: 82-53-744-4301	Germany - Garching
ax: 678-957-1455	China - Hangzhou	Korea - Seoul	Tel: 49-8931-9700
Austin, TX	Tel: 86-571-8792-8115	Tel: 82-2-554-7200	Germany - Haan
el: 512-257-3370	China - Hong Kong SAR	Malaysia - Kuala Lumpur	Tel: 49-2129-3766400
Boston	Tel: 852-2943-5100	Tel: 60-3-7651-7906	Germany - Heilbronn
Vestborough, MA	China - Nanjing	Malaysia - Penang	Tel: 49-7131-72400
el: 774-760-0087	Tel: 86-25-8473-2460	Tel: 60-4-227-8870	Germany - Karlsruhe
ax: 774-760-0088	China - Qingdao	Philippines - Manila	Tel: 49-721-625370
Chicago	Tel: 86-532-8502-7355	Tel: 63-2-634-9065	Germany - Munich
tasca, IL	China - Shanghai	Singapore	Tel: 49-89-627-144-0
el: 630-285-0071	Tel: 86-21-3326-8000	Tel: 65-6334-8870	Fax: 49-89-627-144-44
Fax: 630-285-0075	China - Shenyang	Taiwan - Hsin Chu	Germany - Rosenheim
)allas	Tel: 86-24-2334-2829	Tel: 886-3-577-8366	Tel: 49-8031-354-560
Addison, TX	China - Shenzhen	Taiwan - Kaohsiung	Israel - Ra'anana
el: 972-818-7423	Tel: 86-755-8864-2200	Tel: 886-7-213-7830	Tel: 972-9-744-7705
Fax: 972-818-2924	China - Suzhou	Taiwan - Taipei	Italy - Milan
Detroit	Tel: 86-186-6233-1526	Tel: 886-2-2508-8600	Tel: 39-0331-742611
lovi, MI	China - Wuhan	Thailand - Bangkok	Fax: 39-0331-466781
el: 248-848-4000	Tel: 86-27-5980-5300	Tel: 66-2-694-1351	Italy - Padova
louston, TX	China - Xian	Vietnam - Ho Chi Minh	Tel: 39-049-7625286
el: 281-894-5983	Tel: 86-29-8833-7252	Tel: 84-28-5448-2100	Netherlands - Drunen
ndianapolis	China - Xiamen	161. 04-20-3440-2100	Tel: 31-416-690399
loblesville, IN	Tel: 86-592-2388138		Fax: 31-416-690340
el: 317-773-8323	China - Zhuhai		Norway - Trondheim
ei: 317-773-6323	Tel: 86-756-3210040		Tel: 47-72884388
el: 317-536-2380	Tel. 00-730-3210040		Poland - Warsaw
os Angeles			Tel: 48-22-3325737
lission Viejo, CA			Romania - Bucharest
el: 949-462-9523			Tel: 40-21-407-87-50
Fax: 949-462-9608			
el: 951-273-7800			Spain - Madrid Tel: 34-91-708-08-90
Raleigh, NC			Fax: 34-91-708-08-91
el: 919-844-7510			Sweden - Gothenberg
lew York, NY			Tel: 46-31-704-60-40
el: 631-435-6000			Sweden - Stockholm
San Jose, CA			Tel: 46-8-5090-4654
el: 408-735-9110			UK - Wokingham
el: 408-436-4270			Tel: 44-118-921-5800
Canada - Toronto			Fax: 44-118-921-5820
Геl: 905-695-1980			
ax: 905-695-2078			